

Features

- Operate from 1.65V to 5.5V
- Input and Open-Drain Output
Accept Voltages to 5.5V
- Max tPD of 4 ns at 3.3V
- ESD Protection Exceeds JESD 22
-2000-V Human-Body Model (A114-A)
-200-V Machine Model (A115-A)
-1000-V Charged-Device Model (C101)

General Description

The 74LVC1G06 is a single inverter and its output is an open drain. This device provides the Function $Y = \overline{A}$ in positive logic.

Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant(PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive(SSD): Client and Enterprise
- Wireless Headset, Keyboard, and Mouse

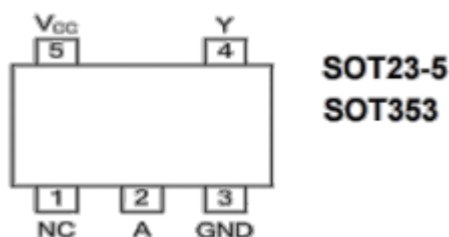
Logic Diagram



Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	Marking
74LVC1G06GV	SOT23-5	Tape and Reel,3000	V06
74LVC1G06GW	SOT353	Tape and Reel,3000	VR

Pin Configuratio



Function Table

INPUT(A)	OUTPUT(Y)
H	L
L	Z

Note: H: High Voltage Level
L: Low Voltage Level
Z: High-Impedance OFF-State

Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	VCC		-0.5 ~ +6.5	V
Input Voltage	VIN		-0.5 ~ +6.5	V
Output Voltage	VOUT		-0.5 ~ +6.5	V
VCC or GND Current	ICC	Output in the Power-off state	±100	mA
Continuous Output Current	IOUT	VOUT=0~VCC	±50	mA
Input Clamp Current	IIK	VIN<0	-50	mA
Output Clamp Current	IOK	VOUT<0	-50	mA
Storage Temperature Range	TSTG		-65 ~ +150	°C
Junction to Ambient	θ_{JA}	SOT-23-5	230	°C/W
		SOT353	280	°C/W

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	VCC	Operating	1.65	--	5.5	V
		Data retention only	1.5	--	--	V
Input Voltage	VIN		0	--	5.5	V
Output Voltage	VOUT	High or low state	0	--	VCC	V
Low-Level Output Current	IOL	VCC=1.65V	--	--	4	mA
		VCC=2.3V	--	--	8	mA
		VCC=3V	--	--	16	mA
		VCC=3V	--	--	24	mA
		VCC=4.5V	--	--	32	mA
Input Transition Rise or Fall ate	$\Delta t/\Delta v$	VCC=1.8V±0.15V, 2.5V±0.2V	--	--	20	ns/V
		VCC=3.3V±0.3V	--	--	10	ns/V
		VCC=5V±0.5V	--	--	5	ns/V
Operating Temperature	TA		-40	--	125	°C

Electrical Characteristics (unless otherwise specified)

PARAMETER	SYM BOL	TEST Conditions	TA=25°C			TA=-40°C~+125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
High-Level Input Voltage	V _{IH}	V _{CC} =1.65V ~ 1.95V	0.65×V _{CC}	--	--	0.65×V _{CC}	--	--	V
		V _{CC} =2.3V ~ 2.7V	1.7	--	--	1.7	--	--	V
		V _{CC} =3V ~ 3.6V	2	--	--	2	--	--	V
		V _{CC} =4.5V ~ 5.5V	0.7×V _{CC}	--	--	0.7×V _{CC}	--	--	V
Low-Level Input Voltage	V _{IL}	V _{CC} =1.65V ~ 1.95V	--	--	0.35×V _{CC}	--	--	0.35×V _{CC}	V
		V _{CC} =2.3V ~ 2.7V	--	--	0.7	--	--	0.7	V
		V _{CC} =3V ~ 3.6V	--	--	0.8	--	--	0.8	V
		V _{CC} =4.5V ~ 5.5V	--	--	0.35×V _{CC}	--	--	0.35×V _{CC}	V
Low-Level Output Voltage	V _{OL}	V _{CC} =1.65 ~ 5.5V, I _{OL} =100μA	--	--	0.1	--	--	0.1	V
		V _{CC} =1.65V, I _{OL} =4mA	--	--	0.45	--	--	0.7	V
		V _{CC} =2.3V, I _{OL} =8mA	--	--	0.3	--	--	0.45	V
		V _{CC} =3.0V, I _{OH} =16mA	--	--	0.4	--	--	0.6	V
		V _{CC} =3.0V, I _{OH} =24mA	--	--	0.55	--	--	0.8	V
		V _{CC} =4.5V, I _{OH} =32mA	--	--	0.55	--	--	0.8	V
Input Leakage Current	I _{I(LEAK)}	V _{CC} =0 ~ 5.5V, V _{IN} =5.5V or GND	--	--	±5	--	--	±5	μA
Power OFF Leakage Current	I _{OFF}	V _{CC} =0V, V _{IN} or V _{OUT} =5.5V	--	--	±10	--	--	±10	μA
Quiescent Supply Current	I _Q	V _{CC} =1.65 ~ 5.5V, V _{IN} =V _{CC} or GND, I _{OUT} =0A	--	--	10	--	--	±10	μA
Additional Quiescent Supply Current Per Input Pin	ΔI _Q	V _{CC} =3 ~ 5.5V, One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND	--	--	500	--	--	500	μA

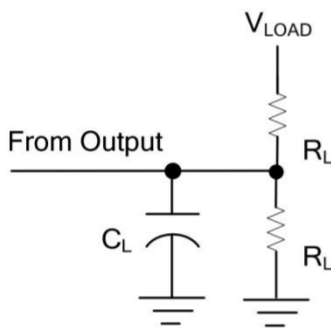
OPERATING CHARACTERISTICS (f=10MHz, TA =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C _{PD}	V _{CC} =1.8V	--	3	--	pF
		V _{CC} =2.5V	--	3	--	pF
		V _{CC} =3.3V	--	4	--	pF
		V _{CC} =5.0V	--	6	--	pF
Input Capacitance	C _I	V _{CC} =3.3V, V _{IN} =V _{CC} or GND	--	4	--	pF
Output Capacitance	C _O	V _{CC} =3.3V, V _{OUT} =V _{CC} or GND	--	5	--	pF

SWITCHING CHARACTERISTICS (unless otherwise specified)

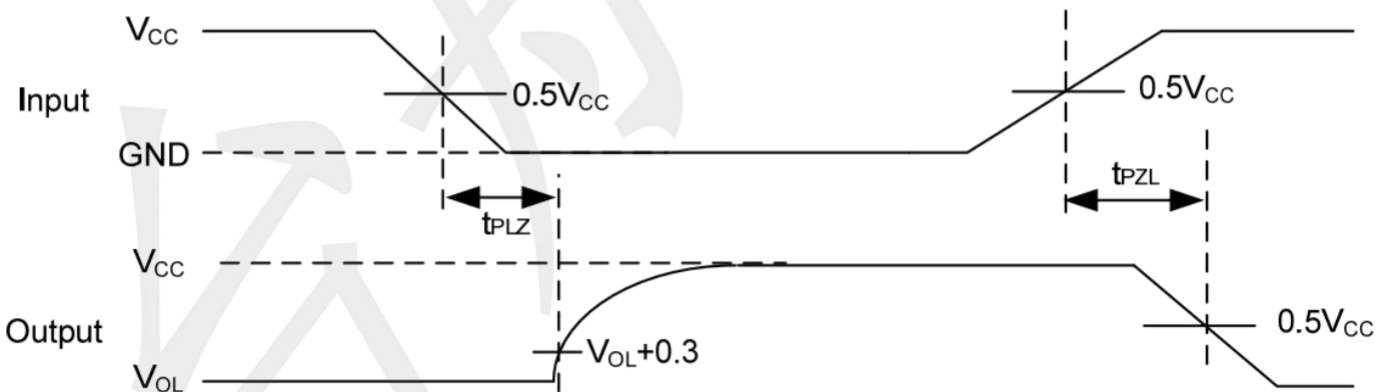
PARAMETER	SYMBOL	TEST Conditions		TA=25°C			TA=-40°C~+125°C			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Propagation delay from input (A or B) to output(Y)	t _{PLH} / t _{PHL}	CL=30pF	V _{CC} =1.8±0.15V , RL=1KΩ	2.2	--	6.5	1.0	--	8.5	nS
			V _{CC} =2.5±0.2V, RL=500Ω	1.1	--	6	0.5	--	6.0	nS
		CL=50pF RL=500Ω	V _{CC} =3.3±0.3V	1.2	--	6	0.5	--	7.0	nS
			V _{CC} =5±0.5V	1	--	5.5	1.0	--	5.5	nS

TEST CIRCUIT AND WAVEFORMS



TEST CIRCUIT

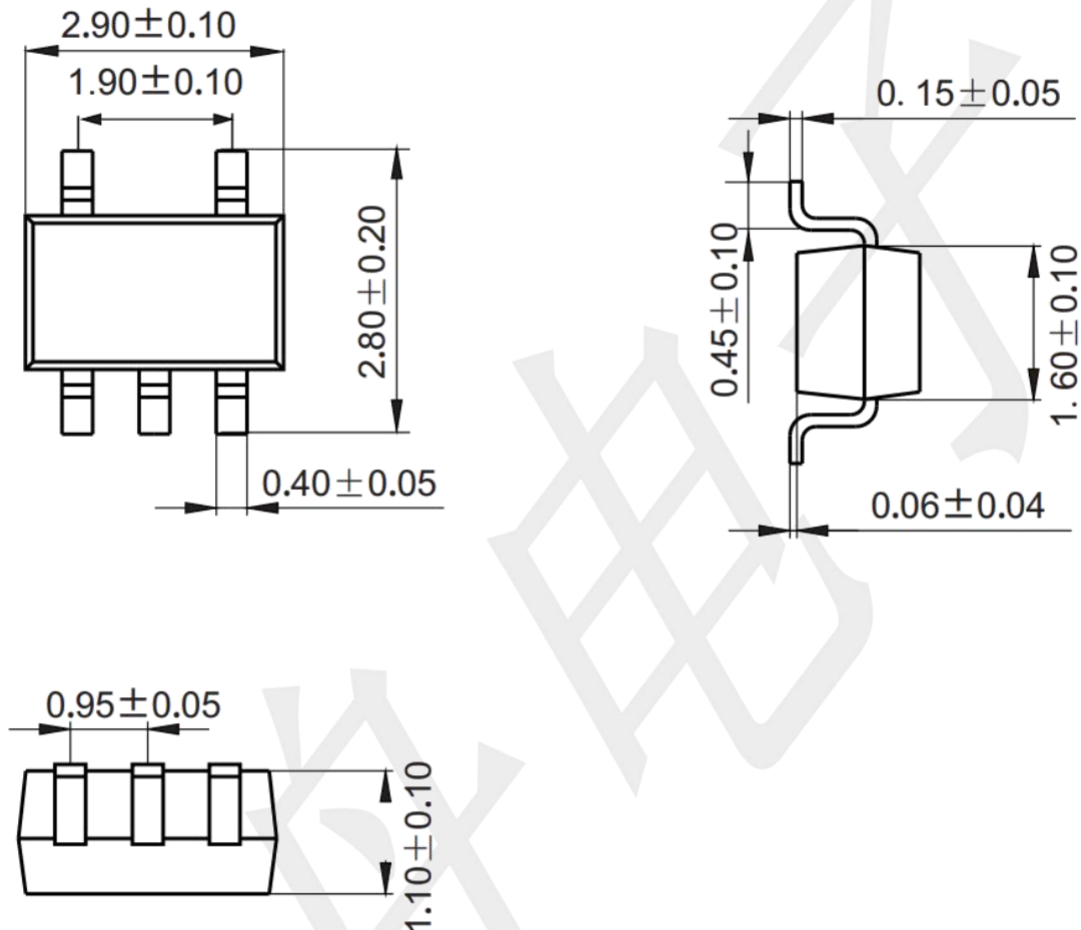
V _{CC}	Inputs		V _M	V _{LOAD}	V _Δ	C _L	R _L
	V _{IN}	t _R , t _F					
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	2 x V _{CC}	0.15V	30pF	1KΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 x V _{CC}	0.15V	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	0.3V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 x V _{CC}	0.3V	50pF	500Ω



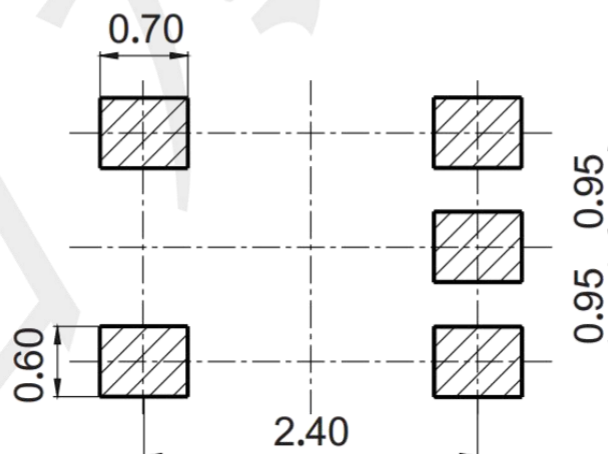
Propagation Delay Times

Package information

SOT23-5 (Unit: mm)

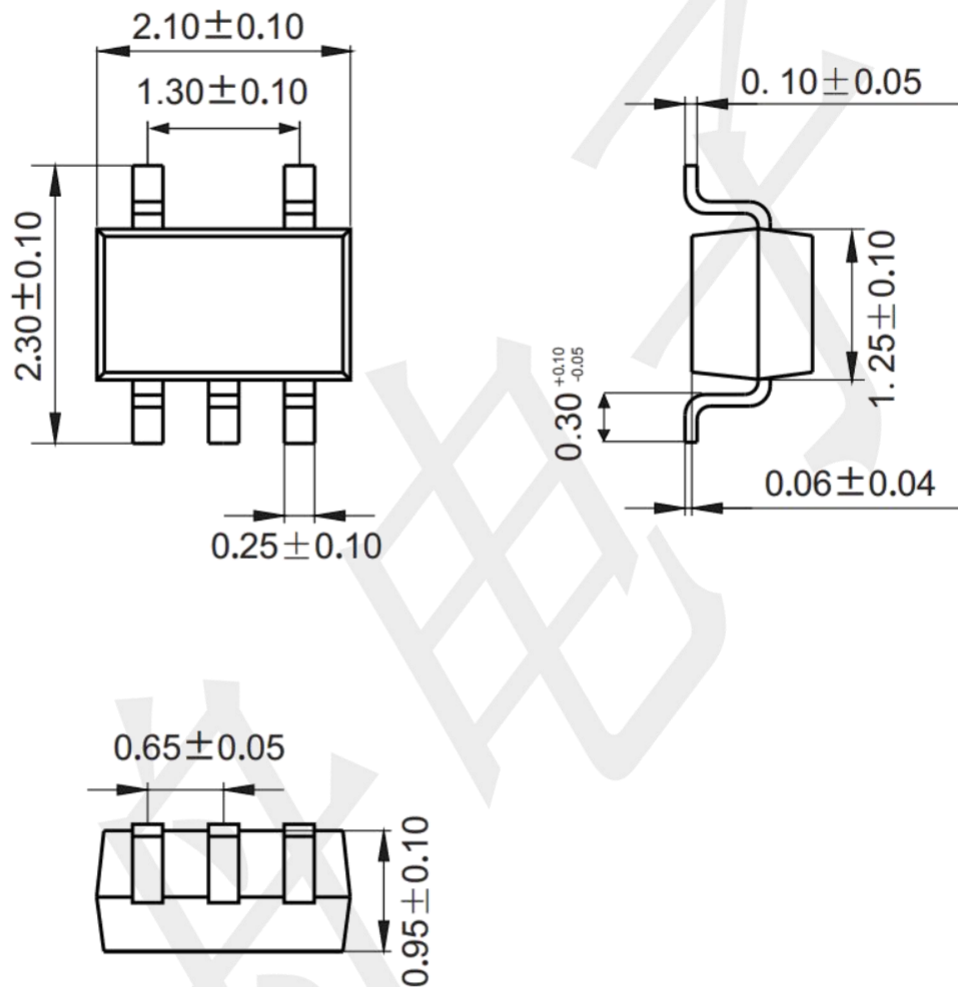


Mounting Pad Layout (unit: mm)



Package information

SOT353 (Unit: mm)



Mounting Pad Layout (unit: mm)

